Wrap-up-teurs view Multiscale and field effect approaches The bridge to design Physics Engineering Micron to millimeter regions nanometer region submicron to micron region **Beyond Moore device cand** Multi scale models based and circuit models g tools  $R_{\rm int}^h$ transport Planar double gate Time Circuit level Vertical CNT transistor

We can simulate transport in molecular structures

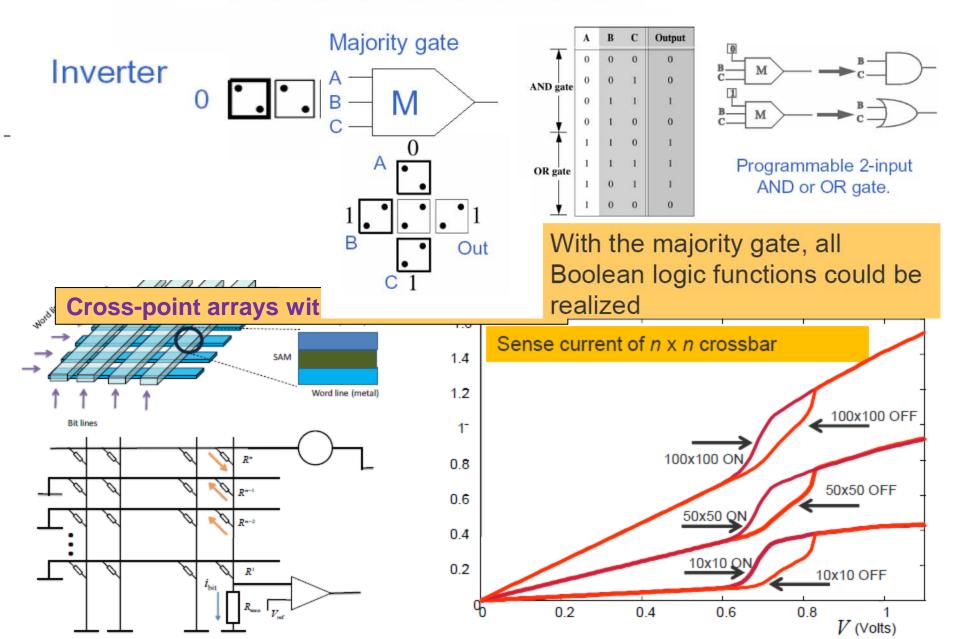
but

the simulation of realistic systems, especially in terms of the contacts and in general the coupling with the external environment is still a problem

## Requirements

- The  $I_{on}/I_{on(1/2)}$  should be 10<sup>4</sup>
- The junction should deliver high currents ideally below 6 V.
- Stability with time (10 years) and to electrical

## Bina Field coupling



## Things that have been discussed

- Who will be the future EDA/CAD vendors? What about MEMS?
  - If there is a need for tools, it will come.
- NanoMagnets seems to be very interesting. What about Nonconductive Molecules?
  - Molecules are an option for the future.
- Are Carbon NanoTubes are dead?
  - No, it depends on the application.
  - Printed CNT transistors are extremily interesting.
  - CNT-network works good as well.
  - Based on Nanotube which are good example
- There are promissing concepts of magenetic amplifiers
  - Cargoso models developed before technology was there
- What about accurracy of single electron devices? There are some promissing results